## Docket No. FIS920030317US1

Inventor:

Anita Madan

Signature:

Anita Madan

01/07/04

Date

Residence:

38 Lindencrest Drive Danbury, CT 06811

Citizenship:

India

Post Office

Address:

Same as residence.

Inventor:

Ashima B. Chakravarti

Signature:

Ashina B. Chakswall

)ate

12/19/03 Date

12/22/01

Residence:

18 Aspen Road

Hopewell Junction, NY 12533

Citizenship:

**USA** 

Post Office

Address:

Same as residence.

Inventor:

Bruce B. Doris

Signature:

Residence:

350 Lake Shore Drive Brewster, NY 10509

Citizenship:

**USA** 

Post Office

Address:

Same as residence.

Inventor:

**Romany Ghali** 

Signature:

Residence:

705 Maple Ave.

Linden, NJ 07036

Citizenship:

**USA** 

Post Office

Address:

Same as residence.

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose information material to the patentability of this application as defined in Title 37, Code of Federal Regulations, §1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Prior U.S. Applications:
Serial No. Filing Date Status
N/A

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

As a named inventor, I hereby appoint the following attorneys and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: Joseph P. Abate, Registration No. 30,328; Jay H. Anderson, Registration No. 38,371; Ira D. Blecker, Registration No. 29,894; Steven Capella, Registration No. 33,086; James J. Cioffi, Registration No. P51,564; Harold H. Huberfeld, Registration No. 26,665; Todd M. C. Li, Registration No. 45,554; Anthony N. Magistrale, Registration No. 35,595; Margaret A. Pepper, Registration No. 45,008; H. Daniel Schnurmann, Registration No. 35,791; Tiffany L. Townsend, Registration No. 43,199; all of INTERNATIONAL BUSINESS MACHINES CORPORATION; John E. Hoel, Registration No. 26,279; Christopher A. Hughes, Registration No. 26,914; Edward A. Pennington, Registration No. 32,588; Joseph C. Redmond, Jr., Registration No. 18,753; all of MORGAN & FINNEGAN, L.L.P.

Send all correspondence to: Ira D. Blecker, Intellectual Property Law, IBM Corporation, Dept. 18G, Building 300-482, 2070 Route 52, Hopewell Junction, New York 12533.

Direct Telephone Calls to: Ira D. Blecker at 845-894-2580

Customer No. 32074

Post Office Address:

Inventor:	Oleg G. Gluschenkov	f
Signature:	Ohesharen	$\frac{12/22/6}{\text{Date}}$
Residence:	160 Academy Street, Apt. 9H Poughkeepsie, NY 12601	
Citizenship:	Russia	
Post Office Address:	Same as residence.	
Inventor:	Michael A. Gribelyuk	1
Signature:	W	$\frac{\frac{2}{8}03}{\text{Date}}$
Residence:	20 Van Scoy Road 155 Kurcherboder Are Poughquag, NY 12570 Stanford C706907 12/18/05 M. F	
Citizenship:	Russia USA	
Post Office Address:	Same as residence.	
Inventor:	Woo-Hyeong Lee	
Signature:	101	12/19/03 Date
Residence:	11 Gold Road Poughquag, NY 12570	
Citizenship:	Korea	

Same as residence.

## Declaration and Power of Attorney for Patent Application

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

## Polycrystalline Silicon Layer With Nano-grain Structure and Method of Manufacture

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application(s) foreign applica	for patent or inve	benefits under Title 35, entor's certificate listed r inventor's certificate h claimed:	below and have also	identified below any
Prior F	oreign Applicati	on(s):		
Numbe	er	Country	Day/Month/Year	Priority Claimed
N/A				